

	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	0	(semiconductor or die or chip or IC) and "titanium hydride" same helium same hydrogen and hermetically near sealed	USPAT	2002/12/09 14:13
2	BRS	1	(semiconductor or die or chip or IC) and "titanium hydride" same helium same hydrogen	USPAT	2002/12/09 14:14
3	BRS	15	(semiconductor or die or chip or IC) and "titanium hydride" and helium same hydrogen	USPAT	2002/12/09 14:15
4	BRS	1	(semiconductor or die or chip or IC) and "titanium hydride" same resistor and (helium or He) same (hydrogen or "H.sub.2")	USPAT	2002/12/09 14:18
5	BRS	1	(semiconductor or die or chip or IC) and "titanium hydride" same resistor same (hydrogen or "H.sub.2") and (helium or He)	USPAT	2002/12/09 14:23
6	BRS	1	(semiconductor or die or chip or IC) and "titanium hydride" same resistor and (hydrogen or "H.sub.2") same (helium or He)	USPAT	2002/12/09 14:24
7	BRS	1	(semiconductor or die or chip or IC) and "titanium hydride" same resistor and (hydrogen or "H.sub.2") same (helium or He)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/09 14:25

	Type	Hits	Search Text	DBs	Time Stamp
8	BRS	1	(semiconductor or die or chip or IC) and ("titanium hydride" or metal near hydride) same resistor and (hydrogen or "H.sub.2") same (helium or He)	USPAT	2002/12/09 14:43
9	BRS	4	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and resistor and (hydrogen or "H.sub.2") same (helium or He)	USPAT	2002/12/09 14:27
10	BRS	5	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and resistor and hermetic\$4	USPAT	2002/12/09 14:45
11	BRS	2	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and resistor and hermetic\$4	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/09 14:39
12	BRS	1	(semiconductor or die or chip or IC) and ("titanium hydride" or metal near hydride) same resistor and (hydrogen or "H.sub.2") same (helium or He) and hermetic\$4	USPAT	2002/12/09 14:44
13	BRS	14	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and helium and hermetic\$4	USPAT	2002/12/09 15:09

	Type	Hits	Search Text	DBs	Time Stamp
14	BRS	94	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and hermetic\$4	USPAT	2002/12/09 14:54
15	BRS	12	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and hydrogen and helium and hermetic\$4	USPAT	2002/12/09 15:30
16	BRS	34	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and hydrogen and helium and hermetic\$4	USPAT	2002/12/09 15:42
17	BRS	32	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and hydrogen and resistor and hermetic\$4	USPAT	2002/12/09 15:57
18	BRS	35	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2") and resistor and hermetic\$4	USPAT	2002/12/10 19:02
19	BRS	291	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2") and resistor	USPAT	2002/12/10 20:01
20	BRS	231	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and hydrogen and hermetic\$4	USPAT	2002/12/09 16:00

	Type	Hits	Search Text	DBs	Time Stamp
21	BRS	231	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and hydrogen and hermetic\$4	USPAT	2002/12/09 20:38
22	BRS	164	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and hydrogen and (resistor or components) and hermetic\$4	USPAT	2002/12/09 20:40
23	BRS	5	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and resistor and hermetic\$4	USPAT	2002/12/09 21:24
24	BRS	42	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and resistor and hermetic\$4	USPAT	2002/12/09 21:34
25	BRS	211	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (resistor or resist\$4) and hermetic\$4	USPAT	2002/12/09 21:35
26	BRS	6	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and (resistor or resist\$4 near (layer or film)) and hermetic\$4	USPAT	2002/12/09 21:41
27	BRS	19	(semiconductor or die or chip or IC) and "titanium hydride" and resistor	USPAT	2002/12/09 21:43

	Type	Hits	Search Text	DBs	Time Stamp
28	BRS	305	(semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and (resistor or resist\$4 near (layer or film)) not ((semiconductor or die or chip or IC) and ("titanium hydride" or (metal near hydride)) and (resistor or resist\$4 near (layer or film))) and hermetic\$4)	USPAT	2002/12/09 21:45
29	BRS	0	(semiconductor or die or chip or IC) and ("TiH.sub.2") and resistor and hermetic\$4	USPAT	2002/12/09 22:37
30	BRS	5	(semiconductor or die or chip or IC) and ("TiH.sub.2") and resistor	USPAT	2002/12/09 22:38
31	BRS	3	(semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2") and resista\$3 near (layer or film)	USPAT	2002/12/09 22:40
32	BRS	0	(semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2" or (metal near hydride)) and (resista\$3 near (layer or film) or resistor)	JPO	2002/12/09 22:41
33	BRS	68	(semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2" or (metal near hydride)) and (resista\$3 near (layer or film) or resistor)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/09 22:43

	Type	Hits	Search Text	DBs	Time Stamp
34	BRS	23	(semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2") and (resista\$3 near (layer or film) or resistor)	USPAT	2002/12/09 22:43
35	BRS	9	air near composition same helium	USPAT	2002/12/10 12:11
36	BRS	0	5569958.pn. and air	USPAT	2002/12/10 12:12
37	BRS	1	5569958.pn.	USPAT	2002/12/10 13:07
38	BRS	0	5569958.pn. and (semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2") and helium and hydrogen	USPAT	2002/12/10 13:08
39	BRS	0	5569958.pn. and (semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2") and hydrogen	USPAT	2002/12/10 13:08
40	BRS	1	5569958.pn. and (semiconductor or die or chip or IC) and ("Titanium hydride" or "TiH.sub.2")	USPAT	2002/12/10 13:43
41	BRS	20	(gas or air) same helium same hydrogen with "5" near ("% " or percents)	USPAT	2002/12/10 14:32
42	BRS	300	(gas or air) same pressure with "5" near "MPa"	USPAT	2002/12/10 14:34
43	BRS	5	(gas or air) same (helium with hydrogen) same pressure with "10" near "MPa"	USPAT	2002/12/10 17:56
44	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "20" near "MPa"	USPAT	2002/12/10 15:12

	Type	Hits	Search Text	DBs	Time Stamp
45	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "40" near "MPa"	USPAT	2002/12/ 10 15:12
46	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "50" near "MPa"	USPAT	2002/12/ 10 15:13
47	BRS	1	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "30" near "MPa"	USPAT	2002/12/ 10 15:13
48	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "6" adj "MPa"	USPAT	2002/12/ 10 15:14
49	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "7" adj "MPa"	USPAT	2002/12/ 10 15:15
50	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "8" adj "MPa"	USPAT	2002/12/ 10 15:15
51	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "9" adj "MPa"	USPAT	2002/12/ 10 15:15
52	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "11" adj "MPa"	USPAT	2002/12/ 10 15:15

	Type	Hits	Search Text	DBs	Time Stamp
53	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "12" adj "MPa"	USPAT	2002/12/ 10 15:15
54	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "13" adj "MPa"	USPAT	2002/12/ 10 15:15
55	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "14" adj "MPa"	USPAT	2002/12/ 10 15:16
56	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "15" adj "MPa"	USPAT	2002/12/ 10 15:16
57	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "16" adj "MPa"	USPAT	2002/12/ 10 15:16
58	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "17" adj "MPa"	USPAT	2002/12/ 10 15:16
59	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "18" adj "MPa"	USPAT	2002/12/ 10 15:16
60	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "19" adj "MPa"	USPAT	2002/12/ 10 15:18

	Type	Hits	Search Text	DBs	Time Stamp
61	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "21" adj "MPa"	USPAT	2002/12/ 10 15:18
62	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "22" adj "MPa"	USPAT	2002/12/ 10 15:18
63	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "23" adj "MPa"	USPAT	2002/12/ 10 15:18
64	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "24" adj "MPa"	USPAT	2002/12/ 10 15:19
65	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "25" adj "MPa"	USPAT	2002/12/ 10 15:19
66	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "26" adj "MPa"	USPAT	2002/12/ 10 15:19
67	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "27" adj "MPa"	USPAT	2002/12/ 10 15:19
68	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "28" adj "MPa"	USPAT	2002/12/ 10 15:19

	Type	Hits	Search Text	DBs	Time Stamp
69	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "29" adj "MPa"	USPAT	2002/12/ 10 15:19
70	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "31" adj "MPa"	USPAT	2002/12/ 10 15:19
71	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "32" adj "MPa"	USPAT	2002/12/ 10 15:19
72	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "33" adj "MPa"	USPAT	2002/12/ 10 15:19
73	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "34" adj "MPa"	USPAT	2002/12/ 10 15:20
74	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "35" adj "MPa"	USPAT	2002/12/ 10 15:20
75	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "36" adj "MPa"	USPAT	2002/12/ 10 15:20
76	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "37" adj "MPa"	USPAT	2002/12/ 10 15:20

	Type	Hits	Search Text	DBs	Time Stamp
77	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "38" adj "MPa"	USPAT	2002/12/ 10 15:20
78	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "39" adj "MPa"	USPAT	2002/12/ 10 15:20
79	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "40" adj "MPa"	USPAT	2002/12/ 10 15:20
80	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "41" adj "MPa"	USPAT	2002/12/ 10 15:20
81	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "42" adj "MPa"	USPAT	2002/12/ 10 15:20
82	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "43" adj "MPa"	USPAT	2002/12/ 10 15:20
83	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "44" adj "MPa"	USPAT	2002/12/ 10 15:20
84	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "45" adj "MPa"	USPAT	2002/12/ 10 15:21

	Type	Hits	Search Text	DBs	Time Stamp
85	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "46" adj "MPa"	USPAT	2002/12/ 10 15:21
86	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "47" adj "MPa"	USPAT	2002/12/ 10 15:21
87	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "48" adj "MPa"	USPAT	2002/12/ 10 15:21
88	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "49" adj "MPa"	USPAT	2002/12/ 10 15:21
89	BRS	0	(chip or die or IC) and (gas or air) same (helium with hydrogen) same pressure with "50" adj "MPa"	USPAT	2002/12/ 10 15:21
90	BRS	3	257/\$.ccls. and (gas or air) with pressure with "10" near "MPa"	USPAT	2002/12/ 10 18:00
91	BRS	0	(chip or die or IC) and under with (lid) same (gas or air) and (gas or air) with pressure with "10" near "MPa"	USPAT	2002/12/ 10 18:02
92	BRS	0	(chip or die or IC or semiconductor near device) and under with (lid) same (gas or air) and (gas or air) with pressure with "10" near "MPa"	USPAT	2002/12/ 10 18:03

	Type	Hits	Search Text	DBs	Time Stamp
93	BRS	0	(chip or die or IC or semiconductor near device) and (lid) and (gas or air) with pressure with "10" near "MPa"	USPAT	2002/12/10 18:03
94	BRS	21	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "10" near "MPa"	USPAT	2002/12/10 18:06
95	BRS	18	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "5" near "MPa"	USPAT	2002/12/10 18:07
96	BRS	12	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "15" near "MPa"	USPAT	2002/12/10 18:08
97	BRS	17	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "20" near "MPa"	USPAT	2002/12/10 18:10
98	BRS	1	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "25" near "MPa"	USPAT	2002/12/10 18:11
99	BRS	18	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "30" near "MPa"	USPAT	2002/12/10 18:12
100	BRS	2	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "35" near "MPa"	USPAT	2002/12/10 18:13
101	BRS	12	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "40" near "MPa"	USPAT	2002/12/10 18:15
102	BRS	1	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "45" near "MPa"	USPAT	2002/12/10 18:16

	Type	Hits	Search Text	DBs	Time Stamp
103	BRS	7	(chip or die or IC or semiconductor near device) and (gas or air) with pressure with "50" near "MPa"	USPAT	2002/12/10 18:17
104	BRS	0	(chip or die or IC or semiconductor near device) and inside with (lid or cover) with pressure with "50" near "MPa"	USPAT	2002/12/10 18:17
105	BRS	0	(chip or die or IC or semiconductor near device) and inside with (lid or cover or cap) with pressure with "50" near "MPa"	USPAT	2002/12/10 18:18
106	BRS	2	(chip or die or IC or semiconductor near device) and inside with (lid or cover or cap) same pressure with "MPa"	USPAT	2002/12/10 18:19
107	BRS	5	(chip or die or IC or semiconductor near device) and inner with (lid or cover or cap) same pressure with "MPa"	USPAT	2002/12/10 18:20
108	BRS	75	(chip or die or IC or semiconductor near device) and (lid or cover or cap) same pressure with "MPa"	USPAT	2002/12/10 18:26
109	BRS	90	257/\$.ccls. and pressure with "MPa"	USPAT	2002/12/10 19:02
110	BRS	0	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2") and resistor and hermetic\$4	JPO	2002/12/10 19:02
111	BRS	0	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2") and resistor	JPO	2002/12/10 19:03

	Type	Hits	Search Text	DBs	Time Stamp
112	BRS	0	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and resistor	JPO	2002/12/10 19:03
113	BRS	468	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride)	JPO	2002/12/10 19:20
114	BRS	52	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and resistance	JPO	2002/12/10 19:33
115	BRS	0	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and resistant near (layer or film)	JPO	2002/12/10 19:34
116	BRS	1	(semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and resistance near (layer or film)	JPO	2002/12/10 19:56
117	BRS	6	01212467.pn. or 5569958.pn. or 6281135.pn. or 5689089.pn. or 5744733.pn. or 5701008.pn.	USPAT; JPO	2002/12/10 19:59
118	BRS	0	(257/721 or 257/722) and (semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2") and resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/10 20:08
119	BRS	1	(257/721 or 257/722) and (semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/10 20:20

	Type	Hits	Search Text	DBs	Time Stamp
120	BRS	0	(257/723 or 257/724) and (semiconductor or die or chip or IC) and ("titanium hydride" or hydride) and (hydrogen or "H.sub.2")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/ 10 20:11
121	BRS	2	(257/723 or 257/724) and (semiconductor or die or chip or IC) and ("titanium hydride" or hydride)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/ 10 20:18
122	BRS	3	(257/721 or 257/722) and (semiconductor or die or chip or IC) and ("titanium hydride" or hydride)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/ 10 20:20